

Vishay Siliconix

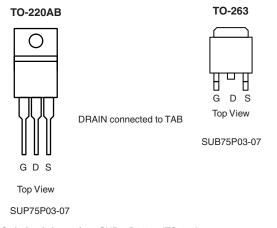
P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY V_{DS} (V) $R_{DS(on)}$ (Ω) I_D (A)^a - 30 0.007 at V_{GS} = - 10 V ± 75 0.010 at V_{GS} = - 4.5 V ± 75

FEATURES

• Compliant to RoHS Directive 2002/95/EC

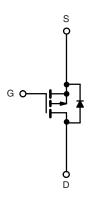




Ordering Information: SUB75P03-07 (TO-263)

SUB75P03-07-E3 (TO-263, Lead (Pb)-free) SUP75P03-07 (TO-220AB)

SUP75P03-07-E3 (TO-220AB, Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)							
Parameter	Symbol	Limit	Unit				
Gate-Source Voltage	V_{GS}	± 20	V				
Continuous Drain Current (T _J = 175 °C)	T _C = 25 °C	1	- 75 ^a	Α			
	T _C = 125 °C	I _D	- 65				
Pulsed Drain Current	I _{DM}	7 ^ !					
Avalanche Current		I _{AR}	- 60				
Repetitive Avalanche Energy ^b	L = 0.1 mH	E _{AR}	180	mJ			
Power Dissipation	T _C = 25 °C (TO-220AB and TO-263)	В	187 ^d	W			
	T _A = 25 °C (TO-263) ^c	P_{D}	3.75]			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C			

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Limit	Unit			
Junction-to-Ambient	PCB Mount (TO-263) ^c	ь	40	°C/W			
	Free Air (TO-220AB)	R _{thJA}	62.5				
Junction-to-Case		R_{thJC}	0.8	1			

Notes:

- a. Package limited.
- b. Duty cycle ≤ 1 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. See SOA curve for voltage derating.

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^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.

SUB75P03-07, SUP75P03-07

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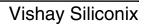


SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 30			V		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	- 1		- 3			
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zero Gate Voltage Drain Current		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$			- 1			
	I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$			- 50	μΑ		
		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			- 250			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 120			Α		
Drain-Source On-State Resistance ^a		V _{GS} = - 10 V, I _D = - 30 A		0.0055	0.007			
	_B	V _{GS} = - 10 V, I _D = - 30 A, T _J = 125 °C			0.010			
	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 30 A, T _J = 175 °C			0.013	Ω		
		V _{GS} = - 4.5 V, I _D = - 20 A		0.008	0.010	1		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 75 A	20			S		
Dynamic ^b								
Input Capacitance	C _{iss}			9000		pF		
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = - 25 V, f = 1 MHz		1565				
Reversen Transfer Capacitance	C _{rss}]		715				
Total Gate Charge ^c	Qg			160	240	nC		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -75 \text{ A}$		32				
Gate-Drain Charge ^c	Q _{gd}			30				
Turn-On Delay Time ^c	t _{d(on)}			25	40	ns		
Rise Time ^c	t _r	$V_{DD} = -15 \text{ V}, R_1 = 0.2 \Omega$		225	360			
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ - 75 A, $V_{GEN} =$ - 10 V, $R_g = 2.5 \Omega$		150	240			
Fall Time ^c	t _f			210	340			
Source-Drain Diode Ratings and Cha	racteristics ^b	(T _C = 25 °C)		•				
Continuous Current	I _S				- 75	А		
Pulsed Current	I _{SM}				- 240			
Forward Voltage ^a	V_{SD}	I _F = - 75 A, V _{GS} = 0 V		- 1.2	- 1.5	V		
Reverse Recovery Time	t _{rr}			55	100	ns		
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 75 A, dl/dt = 100 A/μs		2.5	5	Α		
Reverse Recovery Charge	Q _{rr}]		0.07	0.25	μC		

Notes:

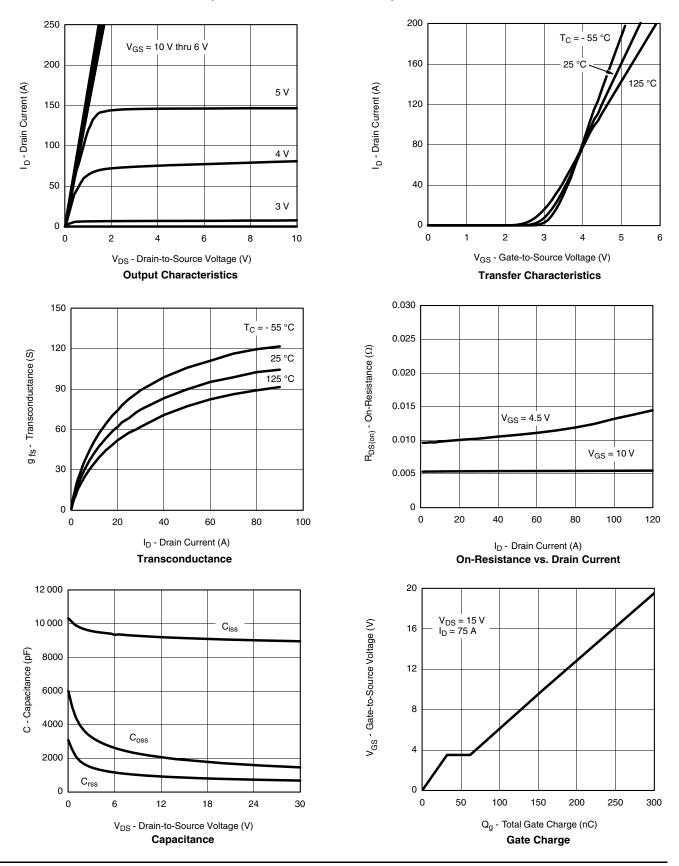
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



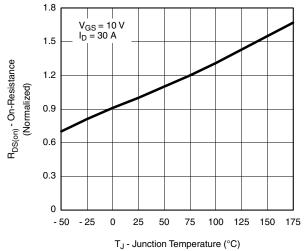
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SUB75P03-07, SUP75P03-07

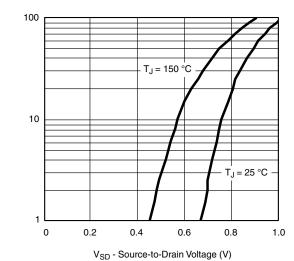
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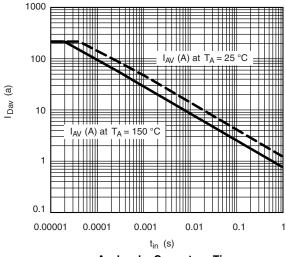


On-Resistance vs. Junction Temperature

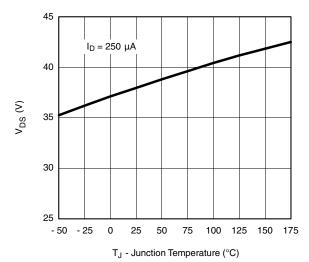


I_S - Source Current (A)

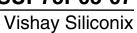
Source-Drain Diode Forward Voltage



Avalanche Current vs. Time

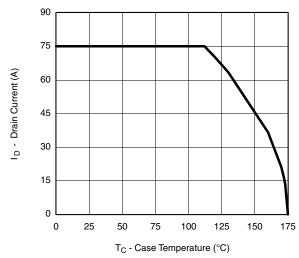


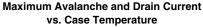
Drain Source Breakdown vs. Junction Temperature

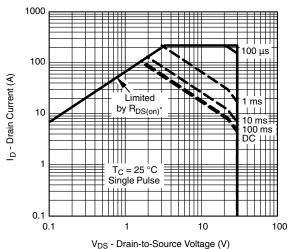




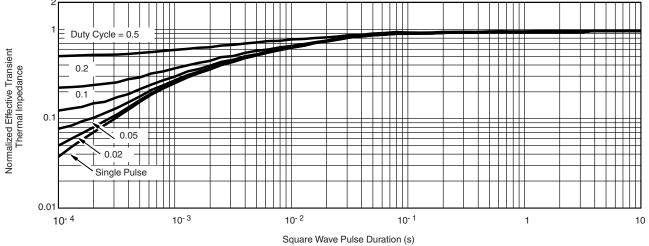
THERMAL RATINGS







* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified **Safe Operating Area**



Normalized Thermal Transient Impedance, Junction-to-Case

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